

TECHNICAL DATA DATA SHEET 4533, REV. B

# HERMETIC SCHOTTKY RECTIFIER Low Forward Voltage Drop

### Features:

- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

# **Maximum Ratings**

| Characteristics                                      | Symbol             | Condition  | Max.        | Units |
|--|--------------------|--|-------------|-------|
| Peak Inverse Voltage                                 | $V_{RWM}$          | -  | 200         | V     |
| Max. Average Forward Current                         | $I_{F(AV)}$        | 50% duty cycle, rectangular wave form (Single)   | 15          | Α     |
| Max. Average Forward Current                         | I <sub>F(AV)</sub> | 50% duty cycle, rectangular wave form (Common Cathode)                                 | 30          | Α     |
| Max. Peak One Cycle Non-<br>Repetitive Surge Current | I <sub>FSM</sub>   | 8.3 ms, half Sine wave (per leg)   | 280         | Α     |
| Non-Repetitive Avalanche Energy                      | E <sub>AS</sub>    | $T_J = 25  ^{\circ}\text{C}, \ I_{AS} = 3.0  \text{A}, \ L = 4.4  \text{mH (per leg)}$ | 20          | mJ    |
| Repetitive Avalanche Current                         | I <sub>AR</sub>    | $I_{AS}$ decay linearly to 0 in 1 $\mu$ s $f$ limited by $T_J$ max $V_A$ =1.5 $V_R$    | 3.0         | А     |
| Maximum Thermal Resistance                           | $R_{	heta JC}$     | DC operation   | 0.85        | °C/W  |
| Max. Junction Temperature                            | TJ                 | -  | -65 to +200 | °C    |
| Max. Storage Temperature                             | $T_{stg}$          | -  | -65 to +200 | °C    |

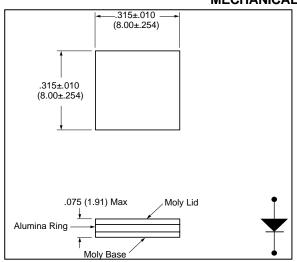
# **Electrical Characteristics**

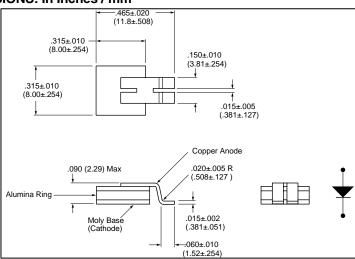
| Characteristics           | Symbol          | Condition                             | Max. | Units |
|---------------------------|-----------------|---------------------------------------|------|-------|
| Max. Forward Voltage Drop | $V_{F1}$        | @ 15A, Pulse, T <sub>J</sub> = 25 °C  | 0.92 | V     |
| (per leg)                 | $V_{F2}$        | @ 15A, Pulse, T <sub>J</sub> = 125 °C | 0.76 | V     |
| Max. Reverse Current      | I <sub>R1</sub> | @V <sub>R</sub> = 200V, Pulse,        | 0.1  | mA    |
|                           |                 | T <sub>J</sub> = 25 °C                |      |       |
| (per leg)                 | I <sub>R2</sub> | @V <sub>R</sub> = 200V, Pulse,        | 1.0  | mA    |
|                           |                 | T <sub>J</sub> = 125 °C               |      |       |
| Max. Junction Capacitance | C <sub>T</sub>  | $@V_R = 5V, T_C = 25  ^{\circ}C$      | 300  | pF    |
| (per leg)                 |                 | $f_{SIG} = 1MHz,$                     |      |       |
|                           |                 | $V_{SIG} = 50 \text{mV (p-p)}$        |      |       |

### **SENSITRON**

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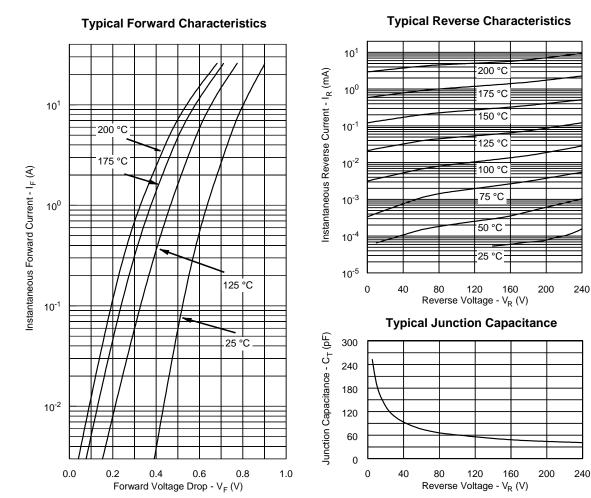
### **MECHANICAL DIMENSIONS: In Inches / mm**





SHD-2B

**Note:** The V<sub>f</sub> curves shown are for the SD125SCU200 unpackaged die only.



#### **SENSITRON**

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